

TOSHIBA Diode Silicon Epitaxial Planar Type

**1SS314**

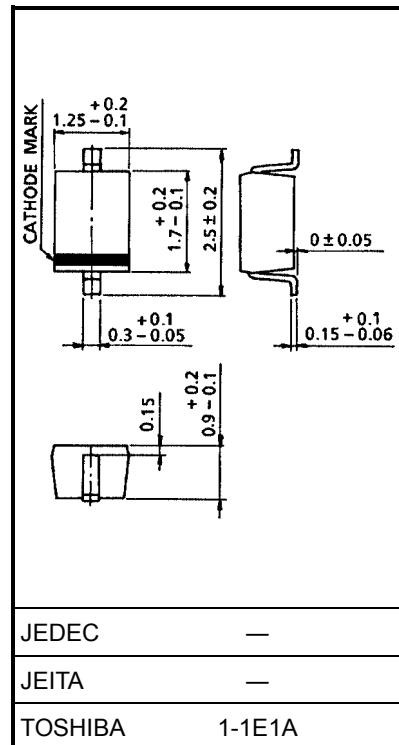
## VHF Tuner Band Switch Applications

Unit: mm

- Small package.
- Small total capacitance:  $C_T = 1.2 \text{ pF}$  (max)
- Low series resistance:  $r_s = 0.5 \Omega$  (typ.)

**Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Reverse voltage	$V_R$	30	V
Forward current	$I_F$	100	mA
Junction temperature	$T_j$	125	°C
Storage temperature range	$T_{stg}$	-55~125	°C

**Electrical Characteristics (Ta = 25°C)**

Weight: 0.004 g (typ.)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Forward voltage	$V_F$	$I_F = 2 \text{ mA}$	—	—	0.85	V
Reverse current	$I_R$	$V_R = 15 \text{ V}$	—	—	0.1	$\mu\text{A}$
Reverse voltage	$V_R$	$I_R = 1 \mu\text{A}$	30	—	—	V
Total capacitance	$C_T$	$V_R = 6 \text{ V}, f = 1 \text{ MHz}$	—	0.7	1.2	pF
Series resistance	$r_s$	$I_F = 2 \text{ mA}, f = 100 \text{ MHz}$	—	0.5	0.9	$\Omega$

**Marking**